



N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Very Low Gate Threshold Voltage (1.0V max)
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 2kV
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.006 grams (approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMN5L06WK-7	SOT-323	3000/Tape & Reel

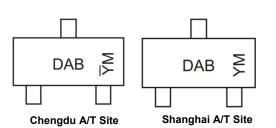
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



DAB = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) $\overline{Y}M$ = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key

Year	2012	2	2013		2014	20	15	2016		2017	2	2018
Code	Z		А		В	(2	D		E		F
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

	Characteristic	Symbol	Value	Unit
Drain Source Voltage		V _{DSS}	50	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current (Note 5)	Continuous Pulsed (Note 6)	ID	300 800	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	250	mW
Thermal Resistance, Junction to Ambient	R _{0JA}	500	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

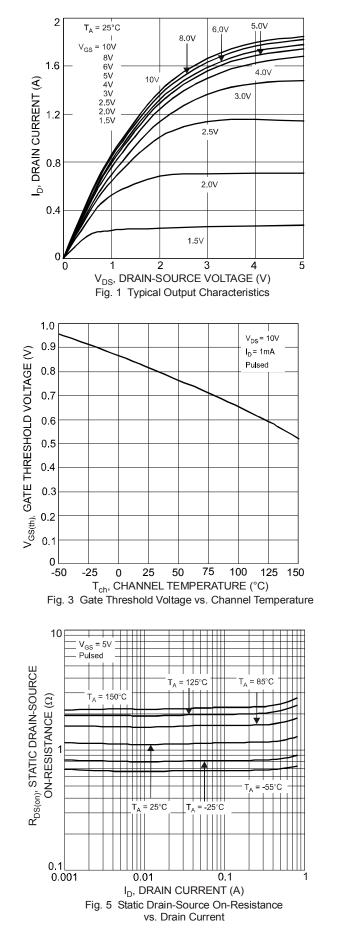
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage		BV _{DSS}	50		_	V	$V_{GS} = 0V, I_{D} = 10\mu A$	
Zero Gate Voltage Drain Current	@T _C = +25°C	IDSS			60	nA	V _{DS} = 50V, V _{GS} = 0V	
					1	μA	V_{GS} = ±12V, V_{DS} = 0V	
Gate-Body Leakage		I _{GSS}			500	nA	V_{GS} = ±10V, V_{DS} = 0V	
					50	nA	V_{GS} = ±5V, V_{DS} = 0V	
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage		V _{GS(th)}	0.49	—	1.0	V	V_{DS} = V_{GS} , I_D = 250 μ A	
			_		3.0		V _{GS} = 1.8V, I _D = 50mA	
Static Drain-Source On-Resistance		R _{DS (ON)}	—	—	2.5	Ω	V_{GS} = 2.5V, I_{D} = 50mA	
				—	2.0		V_{GS} = 5.0V, I_{D} = 50mA	
On-State Drain Current		I _{D(ON)}	0.5	1.4	_	А	V _{GS} = 10V, V _{DS} = 7.5V	
Forward Transconductance		Y _{fs}	200		—	mS	V _{DS} =10V, I _D = 0.2A	
Source-Drain Diode Forward Voltage		V _{SD}	0.5		1.4	V	V _{GS} = 0V, I _S = 115mA	
DYNAMIC CHARACTERISTICS (Note 8)								
Input Capacitance		Ciss			50	pF		
Output Capacitance		Coss	_		25	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance		Crss	_	_	5.0	pF		
Turn-On Delay Time		t _{D(on)}		2.1	—	ns		
Turn-On Rise Time		tr	_	1.8	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$	
Turn-Off Delay Time		t _{D(off)}	_	14.4		ns	$R_{G} = 25\Omega, I_{D} = 200 \text{mA}$	
Turn-Off Fall Time		t _f		8.4	_	ns		

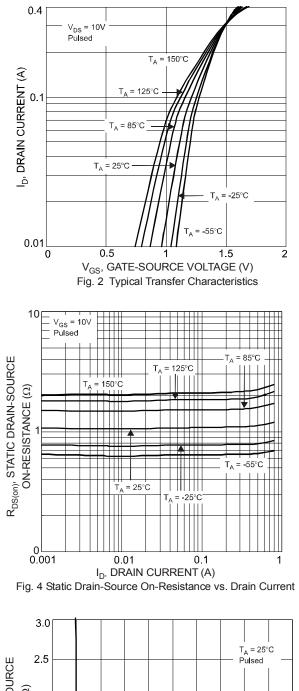
Notes: 5. Device mounted on FR-4 PCB.

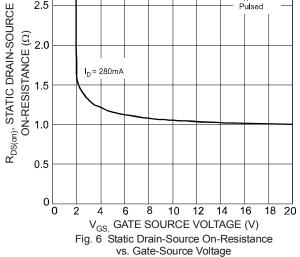
Dulse width ≤10µS, Duty Cycle ≤1%.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.



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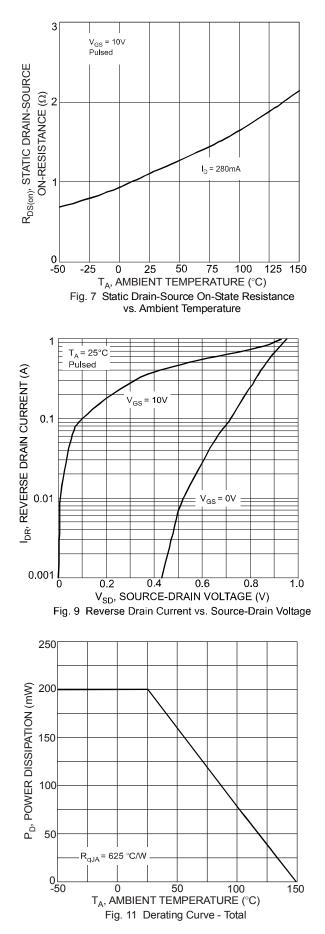




DMN5L06WK Document number: DS30928 Rev. 8 - 2



DMN5L06WK



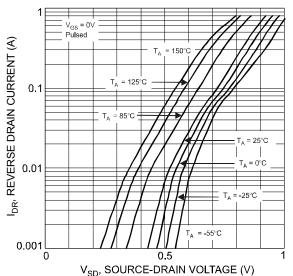
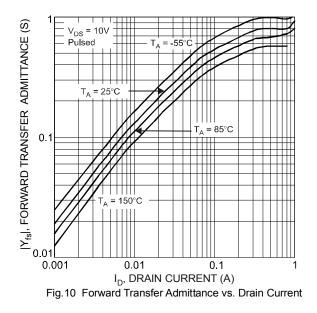


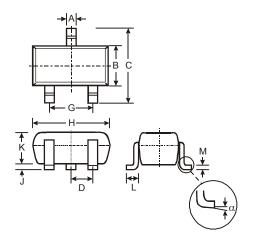
Fig. 8 Reverse Drain Current vs. Source-Drain Voltage





Package Outline Dimensions

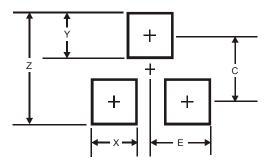
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT-323							
Dim	Min	Max	Тур				
Α	0.25	0.40	0.30				
В	1.15	1.35	1.30				
С	2.00	2.20	2.10				
D	-	-	0.65				
G	1.20	1.40	1.30				
Н	1.80	2.20	2.15				
J	0.0	0.10	0.05				
Κ	0.90	1.00	0.95				
L	0.25	0.40	0.30				
М	0.10	0.18	0.11				
α	0°	8°	-				
All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0



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